![ST logo]

74VHC245

OCTAL BUS
TRANSCEIVER (3-STATE)

- HIGH SPEED: t_{PD} = 4.0 ns (TYP.) at V_{CC} = 5V
- LOW POWER DISSIPATION:
  I_{CC} = 4 µA (MAX.) at T_A=25°C
- HIGH NOISE IMMUNITY:
  V_{NIH} = V_{NIL} = 28% V_{CC} (MIN.)
- POWER DOWN PROTECTION ON CONTROL INPUTS
- SYMMETRICAL OUTPUT IMPEDANCE:
  $|I_{OH}|$ = I_{OL} = 8 mA (MIN)
- BALANCED PROPAGATION DELAYS:
  $t_{PLH} \cong t_{PHL}$
- OPERATING VOLTAGE RANGE:
  V_{CC}(OPR) = 2V to 5.5V
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 245
- IMPROVED LATCH-UP IMMUNITY
- LOW NOISE: V_{OLP} = 0.9V (MAX.)

DESCRIPTION

The 74VHC245 is an advanced high-speed CMOS OCTAL BUS TRANSCEIVER (3-STATE) fabricated with sub-micron silicon gate and double-layer metal wiring C^2MOS technology.

This IC is intended for two-way asynchronous communication between data busses; the

SOP   **TSSOP**
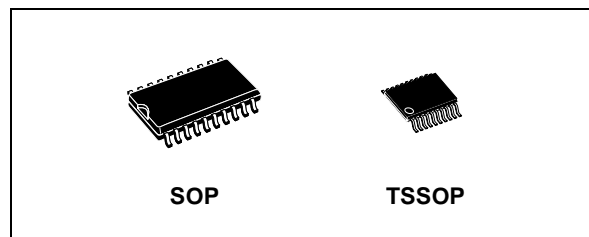
Table 1: Order Codes

PACKAGE	T & R
SOP	74VHC245MTR
TSSOP	74VHC245TTR

direction of data transmission is determined by DIR input. The enable input $\overline{G}$ can be used to disable the device so that the busses are effectively isolated.

All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

All floating bus terminals during High Z State must be held HIGH or LOW.

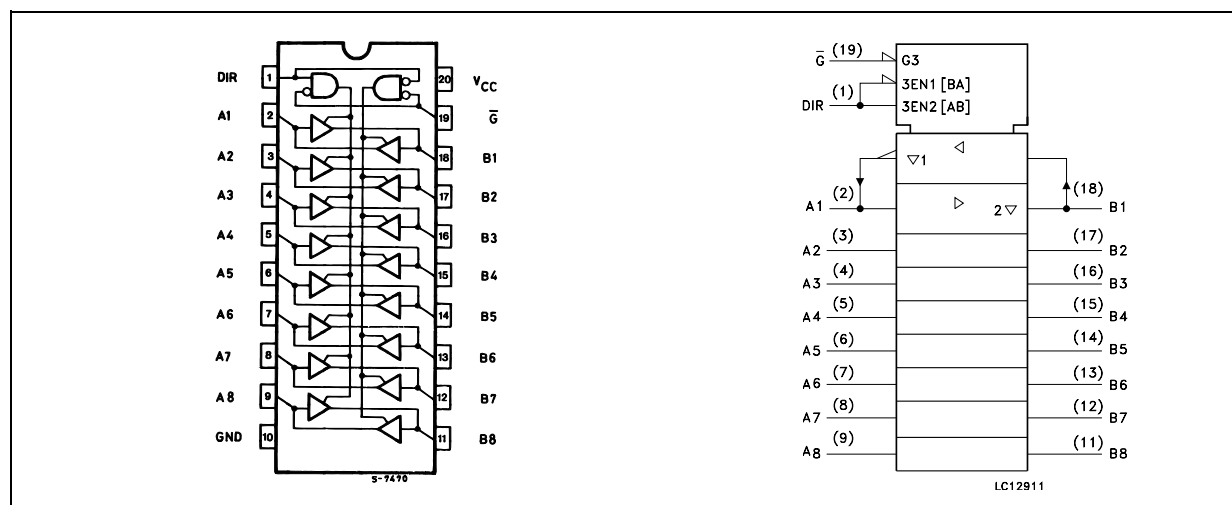**Figure 1: Pin Connection And IEC Logic Symbols**
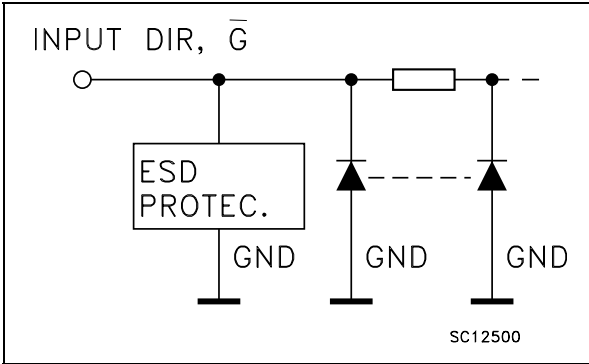
Figure 2: Input Equivalent Circuit

Table 2: Pin Description

PIN N°	SYMBOL	NAME AND FUNCTION
1	DIR	Directional Control
2, 3, 4, 5, 6, 7, 8, 9	A1 to A8	Data Inputs/Outputs
18, 17, 16, 15, 14, 13, 12, 11	B1 to B8	Data Inputs/Outputs
19	$\overline{G}$	Output Enable Input
10	GND	Ground (0V)
20	V_{CC}	Positive Supply Voltage

Table 3: Truth Table

INPUTS		FUNCTION		OUTPUT
$\overline{G}$	DIR	A BUS	B BUS	
L	L	OUTPUT	INPUT	A = B
L	H	INPUT	OUTPUT	B = A
H	X	Z	Z	Z

X : Don't Care
Z : High Impedance

Table 4: Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7.0	V
V_I	DC Input Voltage (DIR, $\overline{G}$)	-0.5 to +7.0	V
$V_{I/O}$	Bus I/O Voltage	-0.5 to V_{CC} + 0.5	V
V_O	DC Output Voltage	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	- 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Current	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 75	mA
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

Table 5: Recommended Operating Conditions

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	2 to 5.5	V
V_I	Input Voltage (DIR, $\overline{G}$)	0 to 5.5	V
$V_{I/O}$	Bus I/O Voltage	0 to V_{CC}	V
V_O	Output Voltage	0 to V_{CC}	V
T_{op}	Operating Temperature	-55 to 125	°C
dt/dv	Input Rise and Fall Time (note 1) (V_{CC} = 3.3 ± 0.3V) (V_{CC} = 5.0 ± 0.5V)	0 to 100 0 to 20	ns/V

1) V_{IN} from 30% to 70% of V_{CC}

Table 6: DC Specifications

Symbol	Parameter	V_{CC} (V)	Test Condition	Value							Unit
				$T_A = 25°C$			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	2.0		1.5			1.5		1.5		V
		3.0 to 5.5		$0.7V_{CC}$			$0.7V_{CC}$		$0.7V_{CC}$		
V_{IL}	Low Level Input Voltage	2.0				0.5		0.5		0.5	V
		3.0 to 5.5				$0.3V_{CC}$		$0.3V_{CC}$		$0.3V_{CC}$	
V_{OH}	High Level Output Voltage	2.0	I_O=-50 µA	1.9	2.0		1.9		1.9		V
		3.0	I_O=-50 µA	2.9	3.0		2.9		2.9		
		4.5	I_O=-50 µA	4.4	4.5		4.4		4.4		
		3.0	I_O=-4 mA	2.58			2.48		2.4		
		4.5	I_O=-8 mA	3.94			3.8		3.7		
V_{OL}	Low Level Output Voltage	2.0	I_O=50 µA		0.0	0.1		0.1		0.1	V
		3.0	I_O=50 µA		0.0	0.1		0.1		0.1	
		4.5	I_O=50 µA		0.0	0.1		0.1		0.1	
		3.0	I_O=4 mA			0.36		0.44		0.55	
		4.5	I_O=8 mA			0.36		0.44		0.55	
I_{OZ}	High Impedance Output Leakage Current	5.5	$V_I = V_{IH}$ or V_{IL} $V_O = V_{CC}$ or GND			±0.25		± 2.5		± 2.5	µA
I_I	Input Leakage Current	0 to 5.5	$V_I = 5.5V$ or GND			± 0.1		± 1		± 1	µA
I_{CC}	Quiescent Supply Current	5.5	$V_I = V_{CC}$ or GND			4		40		40	µA

Table 7: AC Electrical Characteristics (Input $t_r = t_f = 3ns$)

Symbol	Parameter	Test Condition			Value							Unit
		V_{CC} (V)	C_L (pF)		$T_A = 25°C$			-40 to 85°C		-55 to 125°C		
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{PLH} t_{PHL}	Propagation Delay Time	3.3(*)	15			5.8	8.4	1.0	10.0	1.0	10.0	ns
		3.3(*)	50			8.3	11.9	1.0	13.5	1.0	13.5	
		5.0(**)	15			4.0	5.5	1.0	6.5	1.0	6.5	
		5.0(**)	50			5.5	7.5	1.0	8.5	1.0	8.5	
t_{PZL} t_{PZH}	Output Disable Time	3.3(*)	15	$R_L = 1K\Omega$		8.5	13.2	1.0	15.5	1.0	15.5	ns
		3.3(*)	50	$R_L = 1K\Omega$		11.0	16.7	1.0	19.0	1.0	19.0	
		5.0(**)	15	$R_L = 1K\Omega$		5.8	8.5	1.0	10.0	1.0	10.0	
		5.0(**)	50	$R_L = 1K\Omega$		7.3	10.6	1.0	12.0	1.0	12.0	
t_{PLZ} t_{PHZ}	Output Enable Time	3.3(*)	50	$R_L = 1K\Omega$		11.5	15.8	1.0	18.0	1.0	18.0	ns
		5.0(**)	50	$R_L = 1K\Omega$		7.0	9.7	1.0	11.0	1.0	11.0	
t_{OSLH} t_{OSHL}	Output to Output Skew time (note 1)	3.3(*)	50				1.5		1.5		1.5	ns
		5.0(**)	50				1.0		1.0		1.0	

(*) Voltage range is 3.3V ± 0.3V
(**) Voltage range is 5.0V ± 0.5V
Note 1: Parameter guaranteed by design. $t_{soLH} = |t_{pLHm} - t_{pLHn}|$, $t_{soHL} = |t_{pHLm} - t_{pHLn}|$

Table 8: Capacitive Characteristics

Symbol	Parameter	Test Condition			Value							Unit
					$T_A = 25°C$			-40 to 85°C		-55 to 125°C		
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
C_{IN}	Input Capacitance					4	10		10		10	pF
$C_{I/O}$	Output Capacitance					8						pF
C_{PD}	Power Dissipation Capacitance (note 1)					21						pF

1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per circuit)

Table 9: Dynamic Switching Characteristics

Symbol	Parameter	Test Condition		Value							Unit
		V_{CC} (V)		$T_A = 25°C$			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{OLP}	Dynamic Low Voltage Quiet Output (note 1, 2)	5.0			0.6	0.9					V
V_{OLV}				-0.9	-0.6						
V_{IHD}	Dynamic High Voltage Input (note 1, 3)	5.0	$C_L = 50$ pF	3.5							V
V_{ILD}	Dynamic Low Voltage Input (note 1, 3)	5.0				1.5					V

1) Worst case package.
2) Max number of outputs defined as (n). Data inputs are driven 0V to 5.0V, (n-1) outputs switching and one output at GND.
3) Max number of data inputs (n) switching. (n-1) switching 0V to 5.0V. Inputs under test switching: 5.0V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f=1MHz.

Figure 3: Test Circuit

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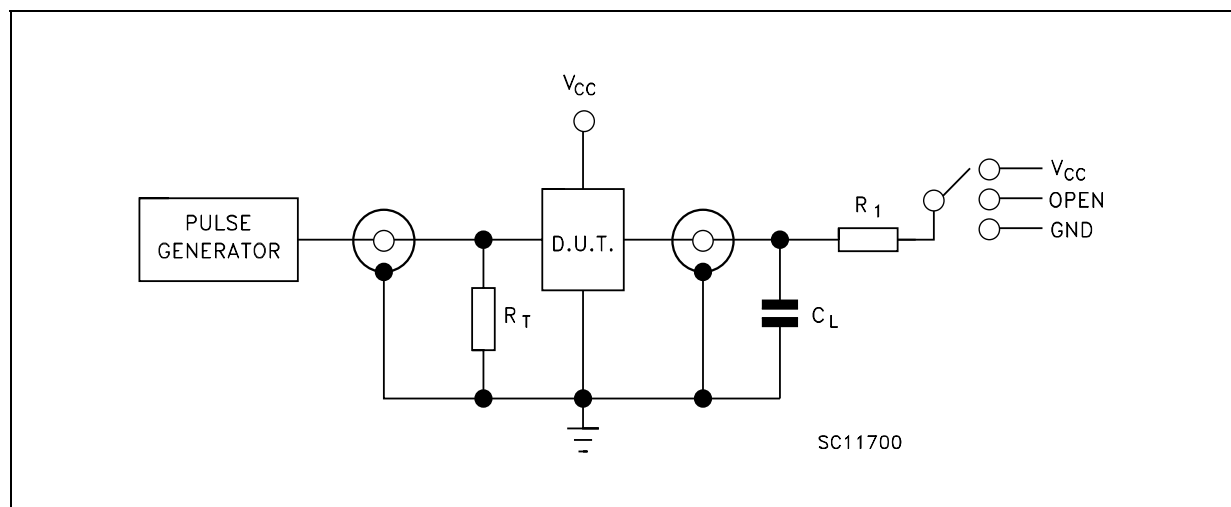
TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	V_{CC}
t_{PZH}, t_{PHZ}	GND

C_L =15/ 50pF or equivalent (includes jig and probe capacitance)
R_L = R_1 = 1KΩ or equivalent
R_T = Z_{OUT} of pulse generator (typically 50Ω)

Figure 4: Waveform - Propagation Delays (f=1MHz; 50% duty cycle)
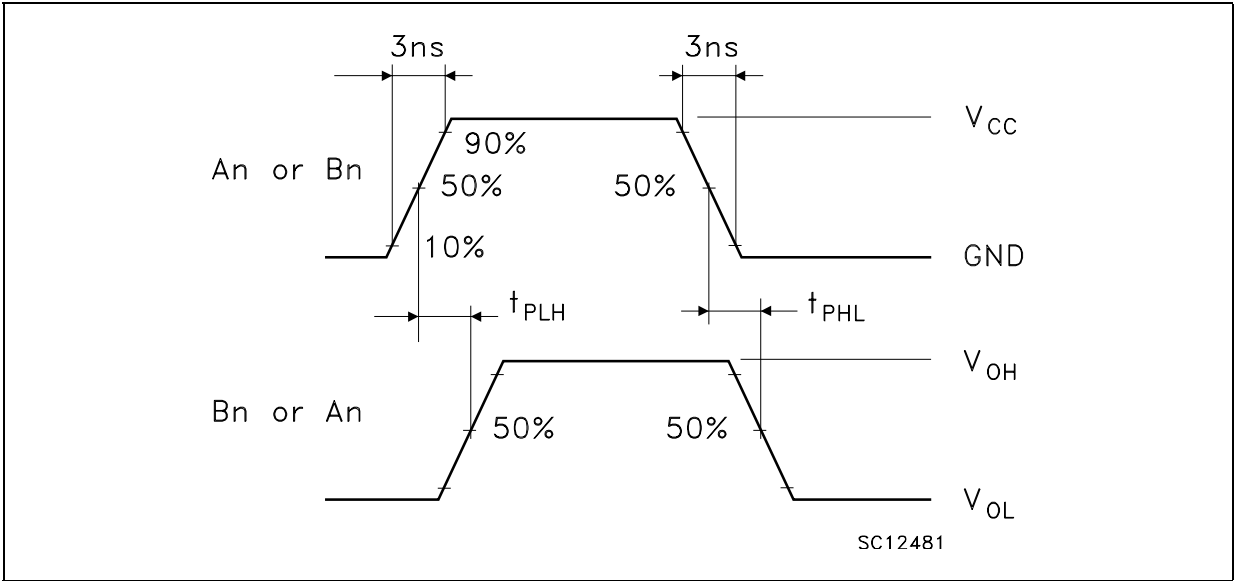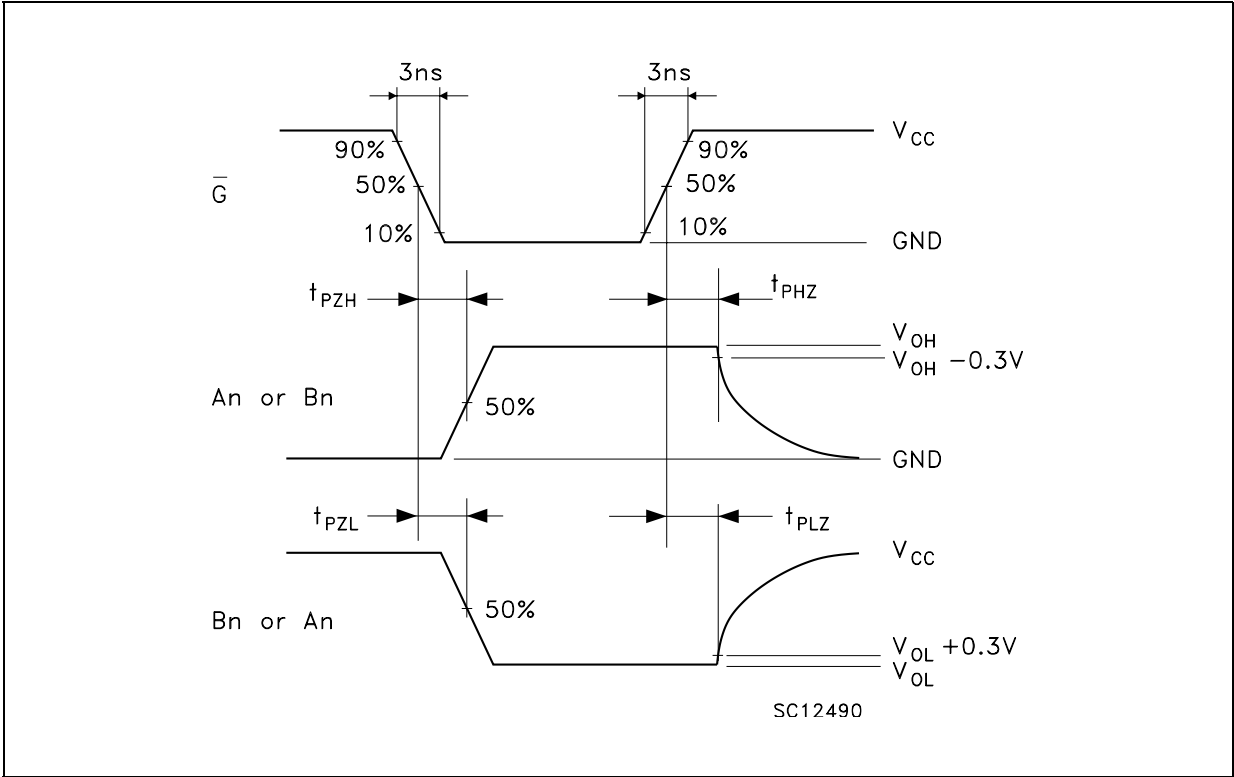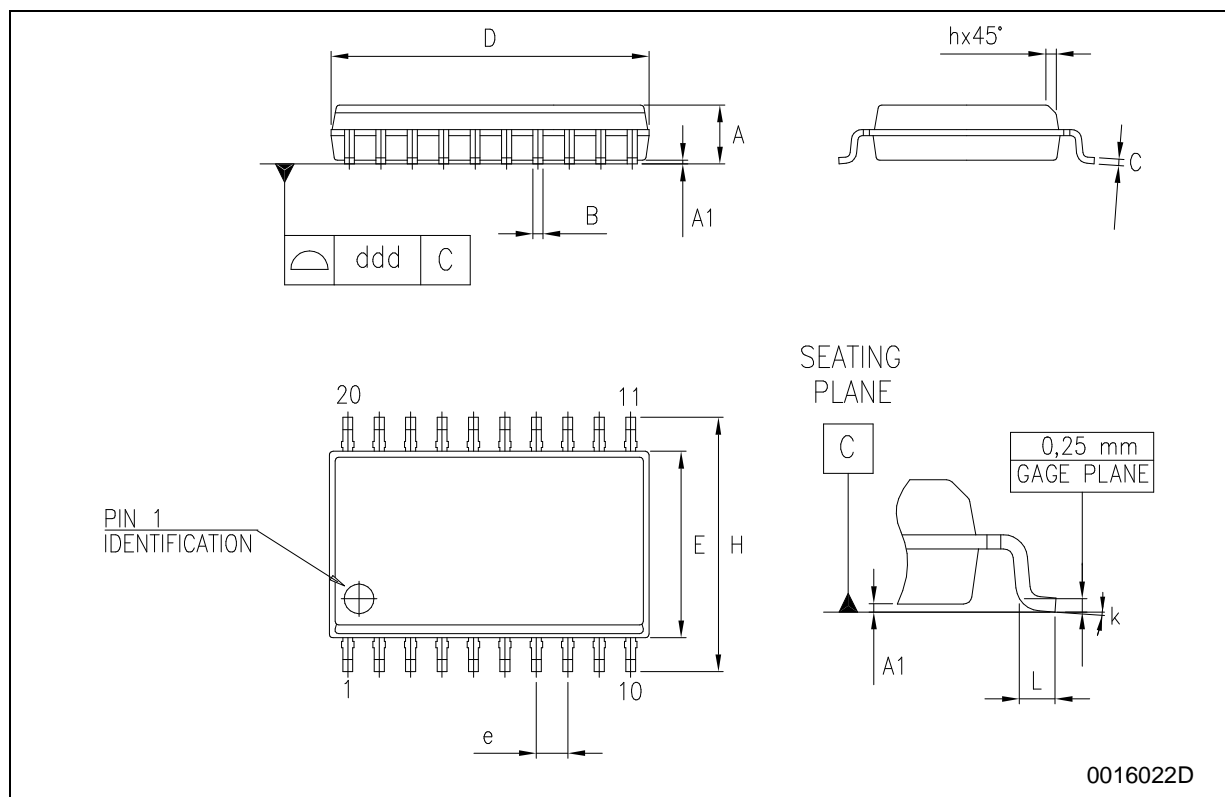

**Figure 5: Waveform - Output Enable And Disable Time** (f=1MHz; 50% duty cycle)

SO-20 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	2.35		2.65	0.093		0.104
A1	0.1		0.30	0.004		0.012
B	0.33		0.51	0.013		0.020
C	0.23		0.32	0.009		0.013
D	12.60		13.00	0.496		0.512
E	7.4		7.6	0.291		0.299
e		1.27			0.050	
H	10.00		10.65	0.394		0.419
h	0.25		0.75	0.010		0.030
L	0.4		1.27	0.016		0.050
k	0°		8°	0°		8°
ddd			0.100			0.004

0016022D

TSSOP20 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	**TYP**	**MAX.**	**MIN.**	**TYP.**	**MAX.**
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0079
D	6.4	6.5	6.6	0.252	0.256	0.260
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0˚		8˚	0˚		8˚
L	0.45	0.60	0.75	0.018	0.024	0.030

PIN 1 IDENTIFICATION

0087225C
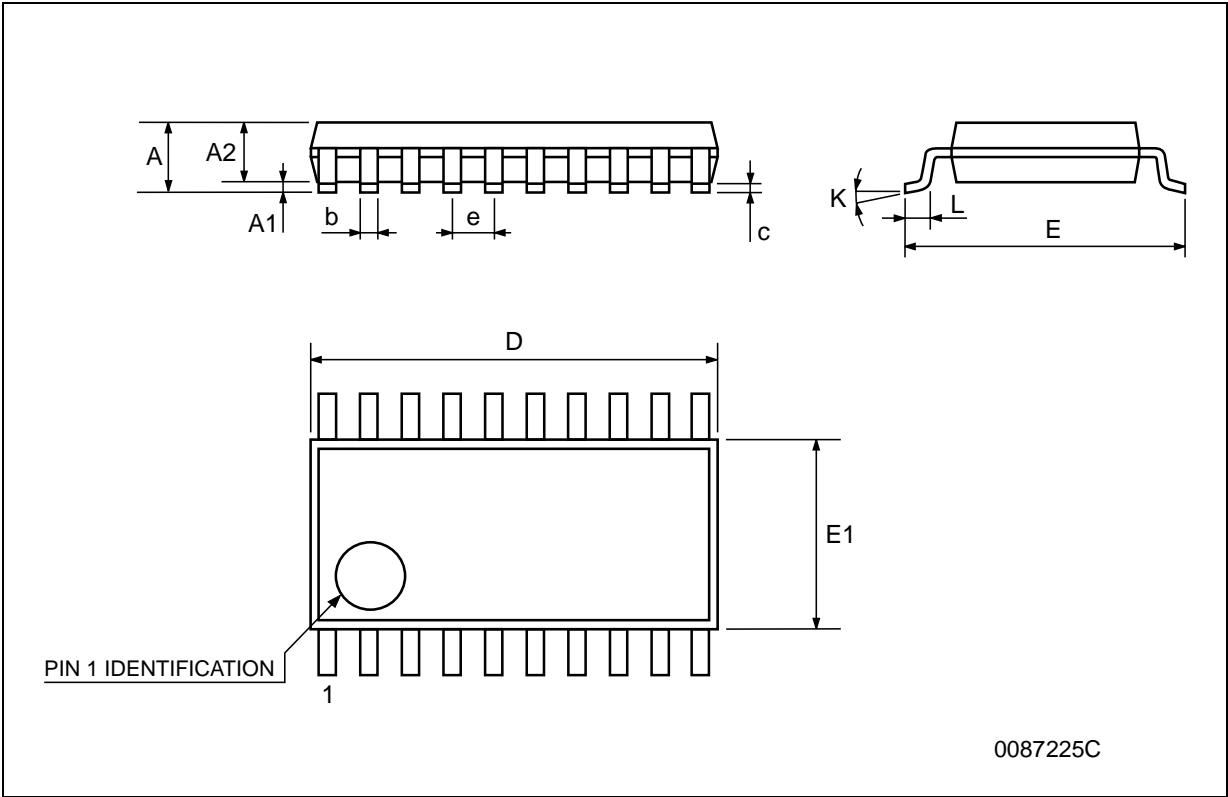
Tape & Reel SO-20 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			30.4			1.197
Ao	10.8		11	0.425		0.433
Bo	13.2		13.4	0.520		0.528
Ko	3.1		3.3	0.122		0.130
Po	3.9		4.1	0.153		0.161
P	11.9		12.1	0.468		0.476

Note: Drawing not in scale
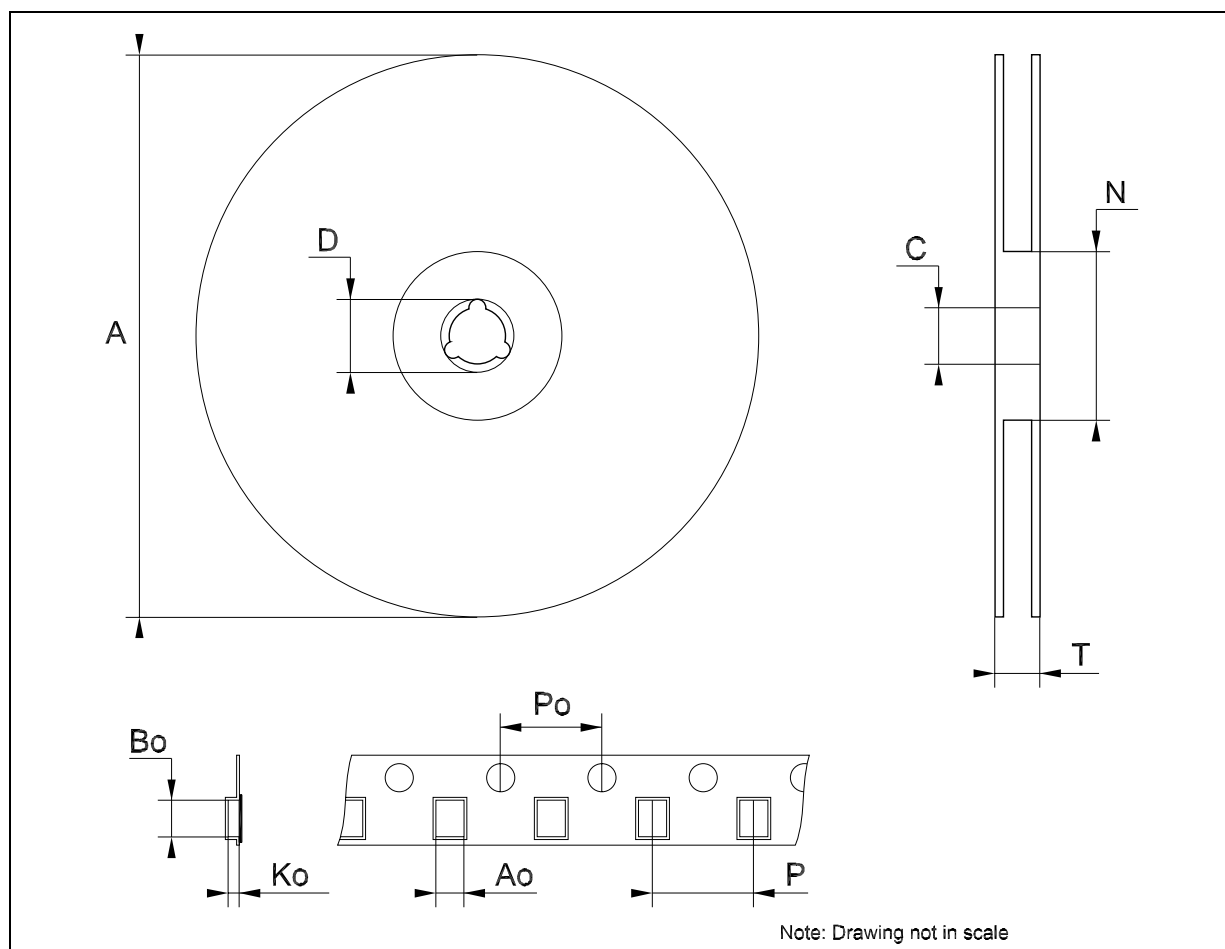
Tape & Reel TSSOP20 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	**TYP**	**MAX.**	**MIN.**	**TYP.**	**MAX.**
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			22.4			0.882
Ao	6.8		7	0.268		0.276
Bo	6.9		7.1	0.272		0.280
Ko	1.7		1.9	0.067		0.075
Po	3.9		4.1	0.153		0.161
P	11.9		12.1	0.468		0.476

Note: Drawing not in scale
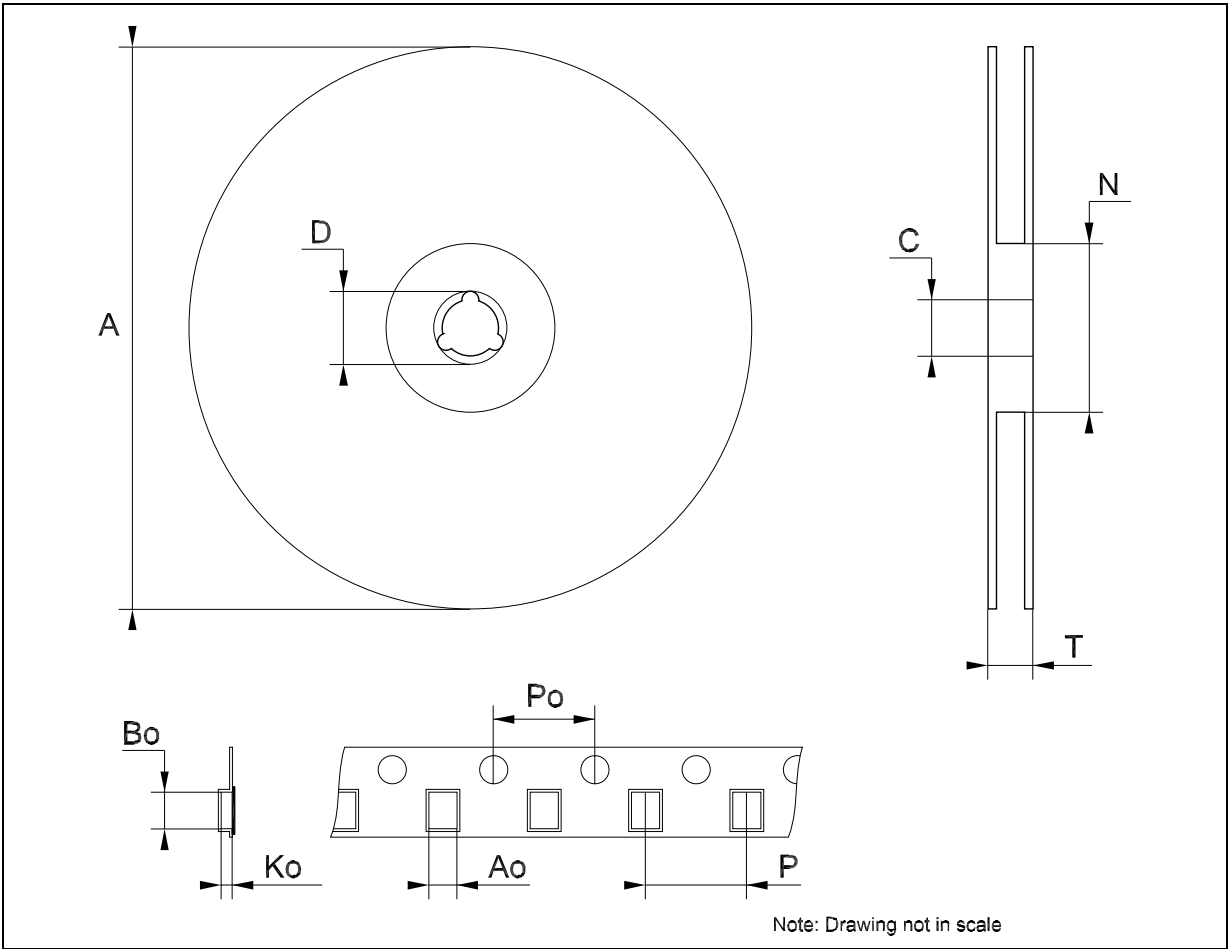
Table 10: Revision History

Date	Revision	Description of Changes
12-Nov-2004	6	Order Codes Revision - pag. 1.